



Micro Commercial Components

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PN2222A

Features

- Continuous Collector Current (I_C) = 600mA.
- Operating and storage temperature range (T_j & T_{stg}) from -55°C ~ $+150^\circ\text{C}$

625mW
NPN General
Purpose Amplifier

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage* ($I_C=10\text{mA}$, $I_B=0$)	40		Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=10\mu\text{A}$, $I_E=0$)	75		Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=10\mu\text{A}$, $I_C=0$)	6.0		Vdc
I_{BL}	Base Cutoff Current ($V_{CE}=60\text{Vdc}$, $V_{BE}=3.0\text{Vdc}$)		20	nAdc
I_{CEX}	Collector Cutoff Current ($V_{CE}=60\text{Vdc}$, $V_{BE}=3.0\text{Vdc}$)		10	nAdc

ON CHARACTERISTICS

h_{FE}	DC Current Gain* ($I_C=0.1\text{mA}$, $V_{CE}=10\text{Vdc}$) ($I_C=1.0\text{mA}$, $V_{CE}=10\text{Vdc}$) ($I_C=10\text{mA}$, $V_{CE}=10\text{Vdc}$) ($I_C=150\text{mA}$, $V_{CE}=10\text{Vdc}$) ($I_C=150\text{mA}$, $V_{CE}=1.0\text{Vdc}$) ($I_C=500\text{mA}$, $V_{CE}=10\text{Vdc}$)	35 50 75 100 50 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=150\text{mA}$, $I_B=15\text{mA}$) ($I_C=500\text{mA}$, $I_B=50\text{mA}$)		0.3 1.0	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C=150\text{mA}$, $I_B=15\text{mA}$) ($I_C=500\text{mA}$, $I_B=50\text{mA}$)	0.6	1.2 2.0	Vdc

SMALL-SIGNAL CHARACTERISTICS

f_T	Current Gain-Bandwidth Product ($I_C=20\text{mA}$, $V_{CE}=20\text{Vdc}$, $f=100\text{MHz}$)	300		MHz
C_{obo}	Output Capacitance ($V_{CB}=10\text{Vdc}$, $I_E=0$, $f=100\text{kHz}$)		8.0	pF
C_{ibo}	Input Capacitance ($V_{BE}=0.5\text{Vdc}$, $I_C=0$, $f=100\text{kHz}$)		25	pF
NF	Noise Figure ($I_C=100\mu\text{A}$, $V_{CE}=10\text{Vdc}$, $R_S=1.0\text{k}\Omega$, $f=1.0\text{kHz}$)		4.0	dB

SWITCHING CHARACTERISTICS

t_d	Delay Time	($V_{CC}=30\text{Vdc}$, $V_{BE}=0.5\text{Vdc}$)	10	ns
t_r	Rise Time	($I_C=150\text{mA}$, $I_B=15\text{mA}$)	25	ns
t_s	Storage Time	($V_{CC}=30\text{Vdc}$, $I_C=150\text{mA}$)	225	ns
t_f	Fall Time	($I_{B1}=I_{B2}=15\text{mA}$)	60	ns

*Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$

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